

United States Patent and Trademark Office

UNITED STATES DEPARTMENT OF COMMERCE United States Patent and Trademark Office Address: COMMISSIONER FOR PATENTS P.O. Dox 1450 Alexandria, Virginia 22313-1450 www.usplo.gov

			www.uspto.gov	
APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTONION	
10/620,713	07/15/2003		ATTORNEY DOCKET NO.	CONFIRMATION NO.
		Scott E. Moore	108298522US1	9587
25096 75	06/02/2004			
PERKINS COIE LLP			EXAMINER	
PATENT-SEA		· · · · ·	ROSENBERGER	R, RICHARD A
P.O. BOX 1247				
SEATTLE, WA			ART UNIT	PAPER NUMBER
,			2877	γ
	e e e		DATE MAILED: 06/02/2004	

Please find below and/or attached an Office communication concerning this application or proceeding.

O)		Application No.	Applicant(s)		
*		10/620,713	MOORE, SCOTT E.		
	Office Action Summary	Examiner	Art Unit		
•		Richard A Rosenberger	2877		
Period fo	- The MAILING DATE of this communication app r Reply	ears on the cover sheet with the	orrespondence addr ss		
A SHO THE N - Extension after S - If the I - If NO - Failuri Any re	DRTENED STATUTORY PERIOD FOR REPLY MAILING DATE OF THIS COMMUNICATION. sions of time may be available under the provisions of 37 CFR 1.13 (b) (6) MONTHS from the mailing date of this communication. period for reply specified above is less than thirty (30) days, a reply period for reply is specified above, the maximum statutory period we to reply within the set or extended period for reply will, by statute, the ply received by the Office later than three months after the mailing dipatent term adjustment. See 37 CFR 1.704(b).	6(a). In no event, however, may a reply be tim within the statutory minimum of thirty (30) days ill apply and will expire SIX (6) MONTHS from cause the application to become ABANDONE	ely filed will be considered timely. the mailing date of this communication. () (35 U.S.C. § 133).		
Status					
1)⊠	Responsive to communication(s) filed on 15 Ma	arch 2004.			
		action is non-final.			
•	Since this application is in condition for allowan		secution as to the merits is		
•	closed in accordance with the practice under E		•		
			4		
Disposition	on of Claims				
5)□ 6)□ 7)□	Claim(s) <u>46-65</u> is/are pending in the application that a polication is of the above claim(s) is/are withdraw claim(s) is/are allowed. Claim(s) <u>46-65</u> is/are rejected. Claim(s) is/are objected to. Claim(s) are subject to restriction and/or	vn from consideration.	*		
Application	on Papers				
9) 🗌 🗇	The specification is objected to by the Examine	r. · *			
10)	The drawing(s) filed on is/are: a)☐ acce	epted or b) \square objected to by the E	Examiner.		
•	Applicant may not request that any objection to the	drawing(s) be held in abeyance. See	e 37 CFR 1.85(a).		
	Replacement drawing sheet(s) including the correcti	ion is required if the drawing(s) is obj	ected to. See 37 CFR 1.121(d).		
11)	The oath or declaration is objected to by the Ex	aminer. Note the attached Office	Action or form PTO-152.		
Dai - ait	ndon 25 H C O S 440	,			
4	nder 35 U.S.C. § 119				
a)[Acknowledgment is made of a claim for foreign All b) Some * c) None of: 1. Certified copies of the priority documents 2. Certified copies of the priority documents 3. Copies of the certified copies of the priorical application from the International Bureau ee the attached detailed Office action for a list	s have been received. s have been received in Applicati ity documents have been receive u (PCT Rule 17.2(a)).	on No ed in this National Stage		
Attachment(s)					
	e of References Cited (PTO-892) e of Draftsperson's Patent Drawing Review (PTO-948)	4) Interview Summary Paper No(s)/Mail Da			
3) Inform	nation Disclosure Statement(s) (PTO-1449 or PTO/SB/08) No(s)/Mail Date		atent Application (PTO-152)		

Art Unit: 2877

Page 2

1. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

- (b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.
- 2. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 3. Claim 46 is rejected under 35 U.S.C. 102(b) as being anticipated by, and claims 47-51 are rejected under 35 U.S.C. 103(a) as being unpatentable over, Van Laarhoven (US 4,946,550).

Figures 2 and 3 in the reference shows a microelectronic substrate assembly comprising a substrate (10), a first layer (2), a second layer (3) and a third layer (5). The first layer (2) is silicon nitride (column 6, line 40), the second layer (3) is silicon dioxide (column 6, lines 36-37), and the third layer (5) is resist (column 6, line 39). The silicon nitride and silicon dioxide layers are inherently different colors because of their different materials. The reference does not disclose the color or

Art Unit: 2877

transparency of the resist; those in the art could choose any known and available resist for the resist in such a structure.

4. Claims 52 and 53 are rejected under 35 U.S.C. 102(b) as being anticipated by, and claims 54-58 are rejected under 35 U.S.C. 103(a) as being unpatentable over Blanchard et al (US 4,145,703).

Blanchard et al shows, in Figure 5 for example, a microelectronic substrate assembly comprising a substrate (10A. 12A. 16A, 20A taken together), a first layer (25A), a second layer (28A) and a third layer (26A) between the first and second layers. The first layer (25A) is silicon nitride (column 7, line 50), the second layer (28A) is silicon dioxide (column 7, line 54), and the third layer (26A) is polysilicon (column 7, line 56). The silicon nitride, silicon dioxide, and polysilicon layers all are inherently different colors because of their different materials. available resist for the resist in such a structure. The instant disclosure and claims do not present the choice of resist as in anyway critical to the structure; not that claims 47-51 differ from each other in the choice of resist.

The reference shows that it is known to make a structure with a silicon nitride layer, a silicon dioxide layer, and a layer of a third material between them. Such multi-layer structures well-known in the art. Those in the art could form such structures using other known materials having other optical characteristics.

Art Unit: 2877

5. Claims 59-65 are rejected under 35 U.S.C. 103(a) as being unpatentable over Lustig et al (US 5,433,651) in view of Shaffer (US 4,755,058).

Lustig et al shows controlling a planarization process by directing light onto the workpiece, monitoring the reflected light during processing, and using the measured reflected light to control the process. In particular the reference mentions the determination of end-points; see column 9, lines 54-60. Although the reference is particularly directed to a particular structure, the method is presented as a general method usable with different materials; note column 9, lines 58-59, which discusses calibrating the machine "to the type of material being polished and the pattern factor of the underlying layer", which at least suggests that other types of materials and other underlying layers can be used with this optical measurement and control system.

It is known in the art that reflectance measurements may advantageously be made at a plurality of different wavelengths to allow better discrimination; see for instant Shaffer, which shows the known technique of providing a plurality different wavelengths in a reflectance measurement (column 6, lines 5-16). It would have been obvious to so use a plurality of different wavelengths with the device or Lustig et al because that reference teaches a reflectance measurement that, as in known, can be advantageously be made with an plurality of wavelengths to better discriminate the difference between the layers as they become exposed through the processing.

Art Unit: 2877

6. Claims 46-58 claim only a structure comprising a substrate having three different layers with some optical characteristics. The preamble language "for use in controlling mechanical and/or chemical planarization processes" is a non-limiting statement of intended use that does not limit the structure claimed. Calling one layer a "sacrificial layer" is nothing more than nomenclature that does not change the claimed structure; a layer made of some material is a layer made of that material whether or not it happens to be termed a "sacrificial layer" or not. Merely renaming the polysilicon layer a "sacrificial layer" does not change the structure nor its optical properties and does not make that previously known structure patentable.

The remarks may well be correct that those in the art would, face with a teaching such as Van Laarhoven, choose the resist layer based upon its suitability of for a photolithographic process rather than primarily for its color. However, it is not true that that reason for the choice will change the optical properties of the chosen resist and make the resist optically indistinguishable from the underlying layer. The instant claims are not limited to resists that are unsuitable for photolithographic processes, and such a limitation cannot be reasonable read into the claims. The fact is that any such structure in which the resist is in fact actually a different color than the underlying layers will meet claim 46 no matter what criteria may have been used for choosing the resist. Any resist that could reasonable

Art Unit: 2877

be chosen for any reason whatsoever would be obvious for that very reason; patent law requires a determination of obviousness, it does not require a determination of obviousness for an applicant's reasons; see *In re Dillon* (CA FC) 16 USPQ2d 1897 (11/9/1990).

7. Applicant's amendment adding new claims necessitated the new ground(s) of rejection presented in this Office action. Accordingly, **THIS ACTION IS MADE**. **FINAL**. See MPEP § 706.07(a). Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the date of this final action.

8. Papers related to this application may be submitted to Group 2800 by facsimile transmission. The faxing of such papers must conform to the notice published in the Official Gazette, 1096 OG 30 (15 November 1989). The fax number is (703) 872-9306

Any inquiry concerning this communication or earlier communications from the examiner should be directed to R. A. Rosenberger whose telephone number is (571) 272-2428.

Any inquiry of a general nature or relating to the status of this application should be directed to the Group receptionist whose telephone number is (703) 308-0956.

R. A. Rosenberger28 May 2004

Richard A. Rosenberger Primary Examiner